







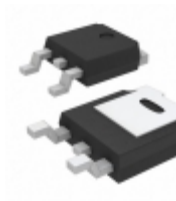
 	<p>Hersteller-Teilenummer: STD28P3LLH6AG</p>
	<p>Hersteller / Marke: STMicroelectronics</p>
<p>Teil der Beschreibung: MOSFET P-CH 30V 12A</p>	<p>Datenblätter:  STD28P3LLH6AG.pdf</p>
<p>RoHs Status: Bleifrei / RoHS-konform</p>	<p>Lagerzustand: New original, 2500 pcs Stock Available.</p>
<p>Lieferung von: Hong Kong</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD28P3LLH6AG
Hersteller	STMicroelectronics
Beschreibung	MOSFET P-CH 30V 12A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2500 pcs Stock
Serie	Automotive, AEC-Q101, STripFET™ H6
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPAK (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	33W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12A (Tc)
Rds On (Max) @ Id, Vgs	30 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	29nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1480pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±18V
Verpackung	Tape & Reel (TR)



































STD28P3LLH6AG ist neu im Original, Suche STD28P3LLH6AG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD28P3LLH6AG STMicroelectronics mit Garantie und Vertrauen. Anfrage STD28P3LLH6AG: Info@Y-IC.com

Sie können auch interessiert sein:

 STD27GK18B Sirectifi IGBT Modules	 STD27GK18 SIRECTIFIER IGBT Modules	 STD29NF03L ST STD29NF03L ST	 STD2805 ST STD2805 ST
 STD2HMK60Z-1 STMicroelectronics MOSFET N-CH 600V 2A IPAK	 STD2HMK60Z STMicroelectronics MOSFET N-CH 600V 2A DPAK	 STD2805T4 STMicroelectronics TRANS PNP 60V 5A DPAK	 STD27N3LH5 STMicroelectronics MOSFET N-CH 30V 27A DPAK

heiße Teile

Mehr

 STD25NE03	 STD25NE03LT4	 STD25NF06L	 STD25NF10	 STD25NF10L
 STD25NF10LA	 STD25NF10LT4	 STD25NF10T4	 STD25NF20	 STD25P03LT4G
 STD2640NL	 STD26NF10	 STD26NF10T4	 STD26P3LLH6	 STD27GK08
 STD27GK08B	 STD27GK12	 STD27GK12B	 STD27GK14	 STD27GK14B
 STD27GK16	 STD27GK16B	 STD27GK18	 STD27GK18B	 STD27N3LH5
 STD29NF03L	 STD29NF03LT4	 STD2HMK60Z	 STD2HMK60Z-1	 STD2HMK60Z-1SK
 STD2HMK60ZT4	 STD2LN60K3	 STD2N52-1	 STD2N62K3	 STD2N95K5
 STD2NA50T4	 STD2NB25T4	 STD2NB40	 STD2NB40-1	 STD2NB50
 STD2NB50T4	 STD2NB52	 STD2NB60	 STD2NB60T4	 STD2NB80
 STD2NB80-1	 STD2NC45-1	 STD2NC50T4-TR	 STD2NC60	 STD2NC60-1

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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